FDS3512 80V N-Channel PowerTrench[®] MOSFET

General Description

SEMICONDUCTOR IM

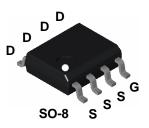
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers.

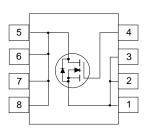
These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable $R_{\text{DS}(\text{ON})}$ specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

Features

- 4.0 A, 80 V $R_{DS(ON)} = 70 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$ $R_{DS(ON)} = 80 \text{ m}\Omega @ V_{GS} = 6 \text{ V}$
- Low gate charge (13nC Typical)
- Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

| Symbol | Parameter | | Ratings | Units |
|-----------------------------------|--|-----------|-------------|-------|
| V _{DSS} | Drain-Source Voltage | | 80 | V |
| V _{GSS} | Gate-Source Voltage | | ±20 | V |
| I _D | Drain Current – Continuous | (Note 1a) | 4.0 | A |
| | - Pulsed | | 30 | |
| P _D | Power Dissipation for Single Operation | (Note 1a) | 2.5 | W |
| | | (Note 1b) | 1.2 | |
| | | (Note 1c) | 1.0 | |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | | -55 to +175 | °C |

| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (N | Note 1a) | 50 | °C/W |
|-----------------|--|----------|----|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case (| (Note 1) | 25 | °C/W |

Package Marking and Ordering Information

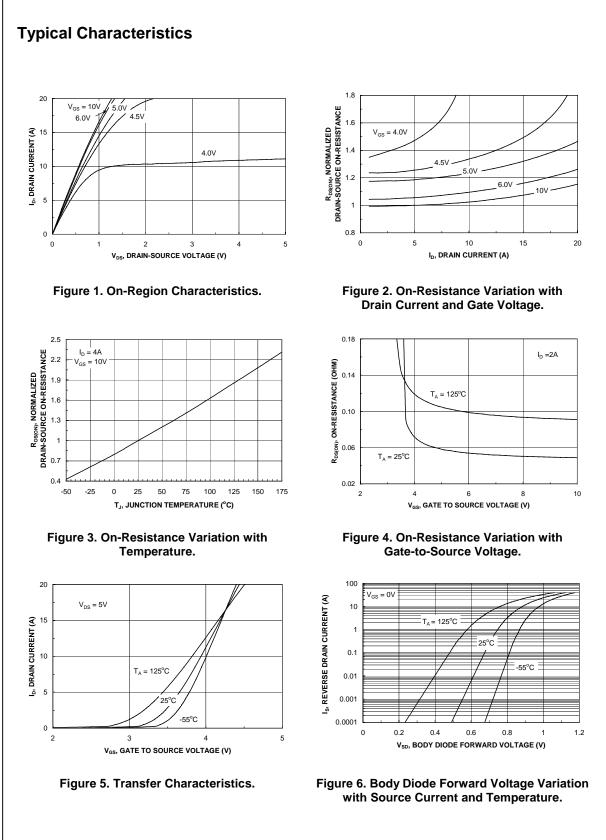
| Device Marking | Device | Reel Size | Tape width | Quantity |
|----------------|---------|-----------|------------|------------|
| FDS3512 | FDS3512 | 13" | 12mm | 2500 units |

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FDS3512

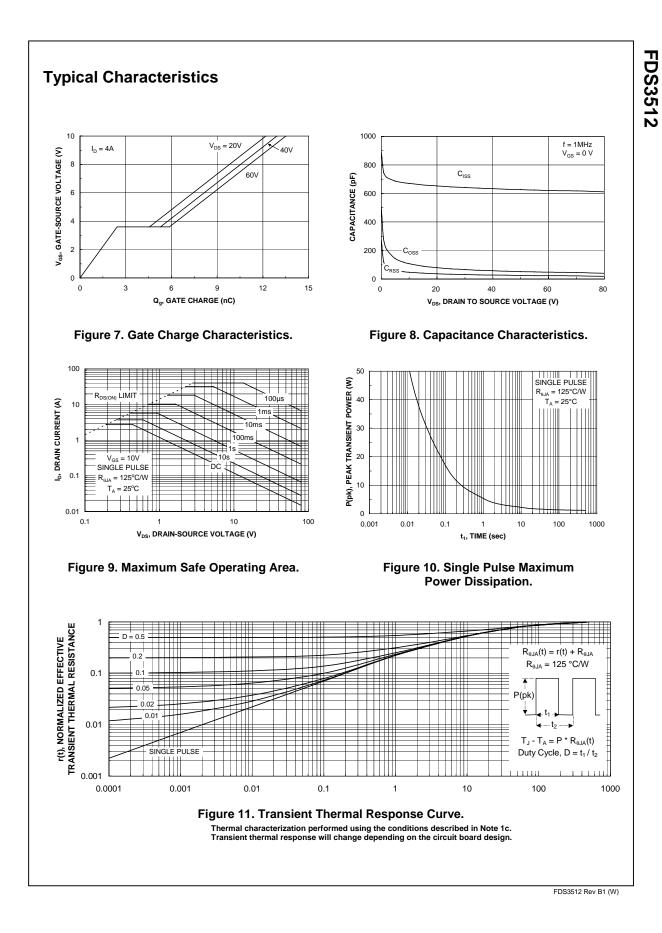
| 90 4.0 1 100 -100 4 | mJ A W/°C μA nA nA |
|------------------------------------|-----------------------------------|
| 4.0 1 100 -100 | A wV/°C μA nA |
| 1 100 -100 | V mV/°C μA nA |
| 1 100 -100 | V mV/°C μA nA |
| 100 -100 | mV/°C μA nA nA |
| 100 -100 | mV/°C μA nA nA |
| 100 -100 | μA nA nA |
| 100 -100 | nA nA |
| -100 | nA nA |
| | |
| 4 | V |
| 4 | V |
| | |
| | mV/°C |
| | |
| 70 80 | mΩ |
| 80 135 | |
| | Α |
| | S |
| | |
| | pF |
| | pF |
| | pF |
| | |
| 14 | ns |
| 6 | ns |
| 38 | ns |
| 8 | ns |
| 18 | nC |
| | nC |
| | nC |
| | |
| 2.1 | Α |
| 1.2 | V |
| | 6 38 8 18 2.1 |

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%



FDS3512 Rev B1 (W)

FDS3512



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|--------------------------|---------------------------|---|
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